

ISC Silicon NPN Power Transistor

2SC4123

DESCRIPTION

- · High Breakdown Voltage-
 - : V_{(BR)CBO}= 1500V(Min)
- · High Switching Speed
- · High Reliability
- · Built-in Damper Diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

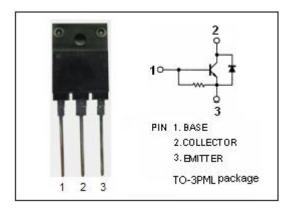


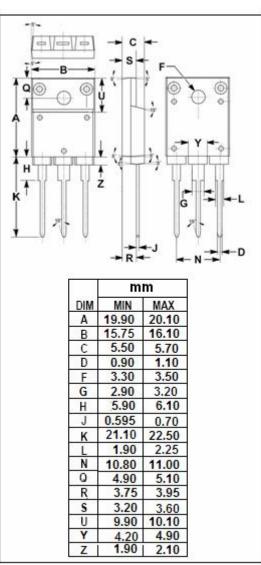
APPLICATIONS

• Ultrahigh-definition CRT display horizontal deflection output applications

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	1500	V	
Vceo	Collector-Emitter Voltage	800	V	
V _{EBO}	Emitter-Base Voltage	6	V	
Ic	Collector Current-Continuous	7	А	
Іср	Collector Current-Peak	16	A	
Pc	Collector Power Dissipation @ T _a =25℃	3.0	W	
	Collector Power Dissipation @ T_c =25 $^{\circ}$ C	60		
TJ	Junction Temperature	ion Temperature 150		
T _{stg}	Storage Temperature Range		$^{\circ}$	







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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL PARAMETER		CONDITIONS	MINI	TYP.	MAX	UNIT		
STWIBUL	PARAWETER	CONDITIONS	MIN	ITP.	IVIAA	UNII		
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C =10mA; I _B = 0	800			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			5.0	V		
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			1.5	V		
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V; I _E = 0			10	μА		
Ices	Collector Cutoff Current	V _{CE} = 1500V; R _{BE} = 0			1.0	mA		
I _{EBO}	Emitter Cutoff Current	V _{EB} = 4V; I _C = 0	40		130	mA		
h _{FE-1}	DC current gain	I _C = 1A; V _{CE} = 5V	8					
h _{FE-2}	DC current gain	I _C = 5A; V _{CE} = 5V	4		6			
Switching times								
t _{stg}	Storage Time	I _C = 5A, I _{B1} = 1A; I _{B2} = -2A			3.0	μS		
t _f	Fall Time	R _L = 33.3 Ω ; V _{CC} = 200V			0.2	μS		

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